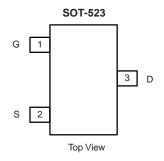
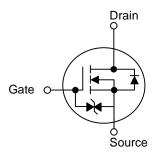


N-Channel 60-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}$ (Ω)	I _D (mA)		
60	2.5 at V _{GS} = 10 V	200		





FEATURES

• Low On-Resistance: 2.5 Ω Low Threshold: 2 V (typ.) Low Input Capacitance: 25 pF Fast Switching Speed: 25 ns Low Input and Output Leakage **DT-Trench Power MOSFET**



BENEFITS

- · Low Offset Voltage
- Low-Voltage Operation

1200V ESD Protection

- Easily Driven Without Buffer
- **High-Speed Circuits**
- Low Error Voltage

APPLICATIONS

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers, Display, Memories, Transistors, etc.
- **Battery Operated Systems**
- Solid-State Relays

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	60		
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current (T _{.I} = 150 °C) ^b	T _A = 25 °C	I_	200		
Continuous Drain Current (1 _J = 150 °C) ³	T _A = 100 °C	- I _D	150	mA	
Pulsed Drain Current ^a	·	I _{DM}	700		
Devices Displie extremb	T _A = 25 °C	- P _D	0.15	W	
Power Dissipation ^b	T _A = 100 °C		0.07		
Maximum Junction-to-Ambient ^b		R _{thJA}	390	°C/W	
Operating Junction and Storage Temperature Range		T _{J,} T _{stg}	- 55 to 150	°C	

Notes:

- a. Pulse width limited by maximum junction temperature.b. Surface Mounted on FR4 board.



			Limits			
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 10 \mu\text{A}$	60			V
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		2.5	V
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 10	μΑ
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 15 \text{ V}$			1	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}$			± 150	nA
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 10 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			± 1000	
		$V_{DS} = 0 \text{ V}, V_{GS} = \pm 5 \text{ V}$			± 100	
7 0 . 1/1 5 . 0		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V , T _J = 125 °C			500	
On-State Drain Current ^a		V _{GS} = 10 V, V _{DS} = 7.5 V	700			mA
	I _{D(on)}	$V_{GS} = 4.5 \text{ V}, V_{DS} = 10 \text{ V}$	300			
Drain-Source On-Resistance ^a		V _{GS} = 10 V, I _D = 100 mA			2.5	Ω
	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 100 \text{ mA}$			4	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 100 mA	100			mS
Diode Forward Voltage	V_{SD}	I _S = 100 mA, V _{GS} = 0 V			1.3	V
Dynamic ^a	<u>'</u>			I		ı
Total Gate Charge	Qg	V_{DS} = 10 V, V_{GS} = 4.5 V $I_{D} \cong 100 \text{ mA}$		0.4	0.6	nC
Input Capacitance	C _{iss}			30		pF
Output Capacitance	C _{oss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}$		6		
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		2.5		
Switching ^{a, b, c}						
Turn-On Time	t _{d(on)}	$V_{DD} = 30 \text{ V}, R_{L} = 150 \Omega$			25	
Turn-Off Time	t _{d(off)}	$I_D \cong 100 \text{ mA}, V_{GEN} = 10 \text{ V}, R_G = 10 \Omega$			35	ns

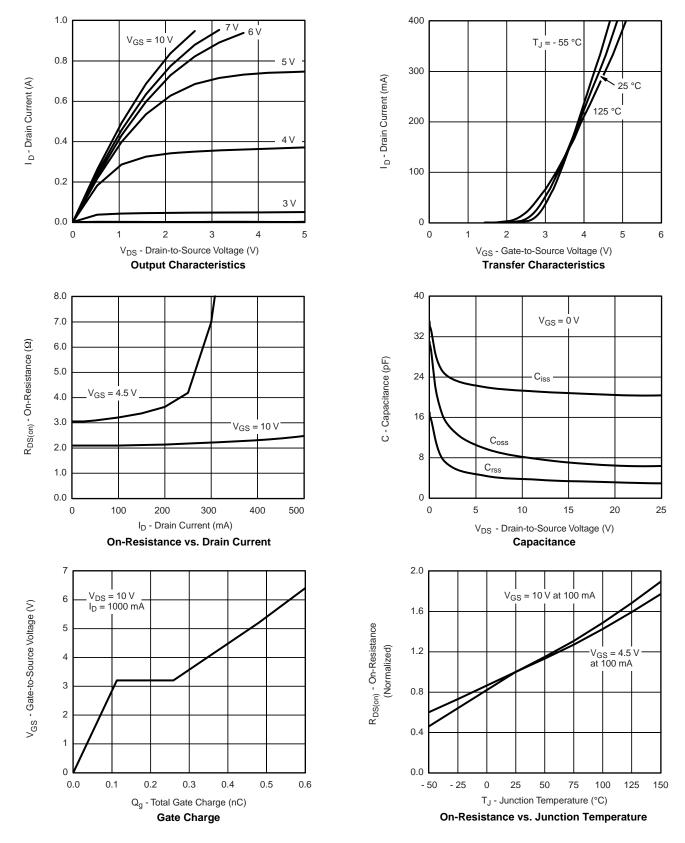
Notes:

- a. For DESIGN AID ONLY, not subject to production testing. b. Pulse test: PW \leq 300 μ s duty cycle \leq 2 %.
- c. Switching time is essentially independent of operating temperature.

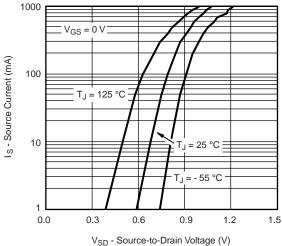
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



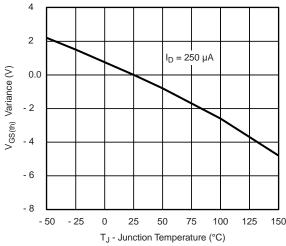
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



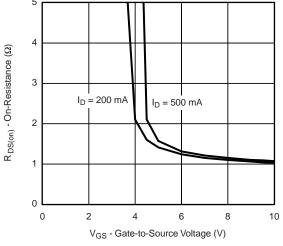
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



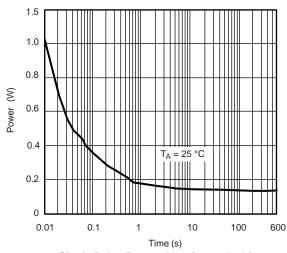
Source-Drain Diode Forward Voltage



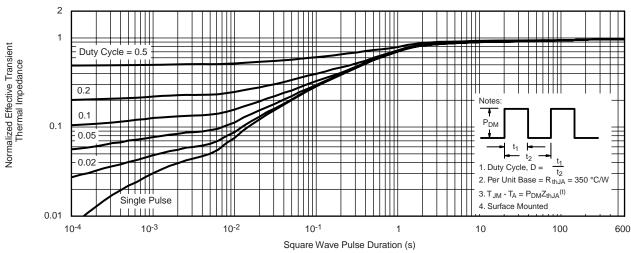
Threshold Voltage Variance Over Temperature



On-Resistance vs. Gate-Source Voltage



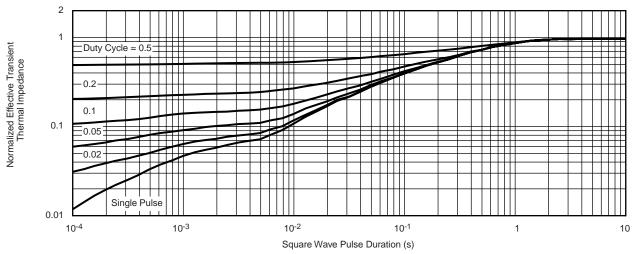
Single Pulse Power, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



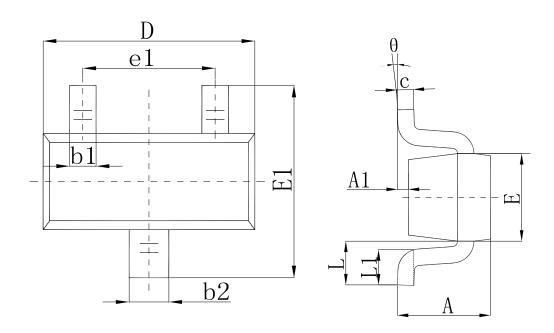
Normalized Thermal Transient Impedance, Junction-to-Foot

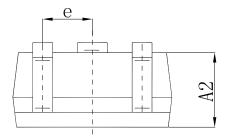
Note

- · The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

DTS7002 www.din-tek.jp

SOT-523 PACKAGE OUTLINE





COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

	Dim in mm			
Symbol	Min	Nor	Max	
A	0.70	0.80	0. 90	
A1	0.00	0.05	0. 10	
A2	0. 70	0.75	0.80	
b1	0. 15	0. 22	0. 29	
b2	0. 25	0.32	0. 39	
С	0. 10	0. 15	0. 20	
D	1.50	1.60	1. 70	
E	1.45	1.60	1. 75	
E1	0. 70	0.80	0. 90	
е	0. 500TPY.			
e1	0. 90	1.00	1. 10	
L	0. 26	0.36	0.46	
L1	0. 400REF.			
θ	0°	4°	8°	





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